Vishay Semiconductors

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Hyperfast Rectifier, 8 A FRED Pt[®]



TO-252AA (D-PAK)

	○ 2, 4	
) 1 1/C	3 O Anode	

PRODUCT SUMMARY					
Package	TO-252AA (D-PAK)				
I _{F(AV)}	8 A				
V _R	600 V				
V _F at I _F	1.3 V				
t _{rr} (typ.)	18 ns				
T _J max.	175 °C				
Diode variation	Single die				

FEATURES

- Hyperfast recovery time, reduced Qrr and soft recovery
- 175 °C maximum operating junction temperature
- For PFC CRM/CCM operation
- Low forward voltage drop
- Low leakage current
- AEC-Q101 qualified
- Meets JESD 201 class 2 whisker test
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

DESCRIPTION / APPLICATIONS

State of the art hyperfast recovery rectifiers designed with optimized performance of forward voltage drop, hyperfast recovery time, and soft recovery.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in PFC boost stage in the AC/DC section of SMPS inverters or as freewheeling diodes. Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Peak repetitive reverse voltage	V _{RRM}		600	V		
Average rectified forward current	I _{F(AV)}	T _C = 143 °C	8			
Non-repetitive peak surge current	I _{FSM}	T _J = 25 °C	90	А		
Peak repetitive forward current	I _{FM}	$T_{C} = 143 \ ^{\circ}C, f = 20 \ kHz, d = 50 \ \%$	16			
Operating junction and storage temperatures	T _J , T _{Stg}		-65 to +175	°C		

ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Breakdown voltage, blocking voltage	V _{BR} , V _R	$I_{B} = I U U U A$		-	-		
Forward voltage	VF	I _F = 8 A	-	2.0	2.4	V	
Forward voltage VF		I _F = 8 A, T _J = 150 °C	-	1.3	1.8		
		$V_{R} = V_{R}$ rated	-	-	50		
Reverse leakage current I _R		$T_J = 150 \text{ °C}, V_R = V_R \text{ rated}$	-	-	500	μA	
Junction capacitance	CT	V _R = 600 V	-	8	-	pF	
Series inductance	L _S	Measured lead to lead 5 mm from package body	-	8	-	nH	

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RoHS COMPLIANT

HALOGEN

FREE



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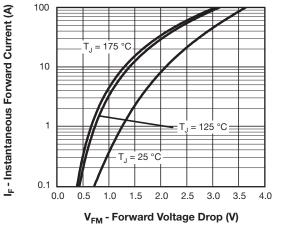
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DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 $^{\circ}$ C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CO	NDITIONS	MIN.	TYP.	MAX.	UNITS
		$I_F = 1 \text{ A}, dI_F/dt = 50$	0 A/μs, V _R = 30 V		21		
Povorso rocovoru timo	+	$I_F = 1 \text{ A}, dI_F/dt = 10$	$I_F = 1 \text{ A}, \text{ d}I_F/\text{d}t = 100 \text{ A}/\mu\text{s}, \text{ V}_R = 30 \text{ V}$		18	22	ns
Reverse recovery time	t _{rr}	T _J = 25 °C	I _F = 8 A dI _F /dt = 200 A/μs V _R = 390 V	-	25	-	115
		T _J = 125 °C		-	34	-	
Peak recovery current	I _{RRM}	T _J = 25 °C		-	3.3	-	А
		T _J = 125 °C		-	4.8	-	A
Reverse recovery charge	Q _{rr}	T _J = 25 °C		-	39	-	nC
		T _J = 125 °C		-	90	-	

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Maximum junction and storage temperature range	T _J , T _{Stg}		-65	-	175	°C
Thermal resistance, junction to case per leg	R _{thJC}		-	1.8	2.2	°C/W
Approximate weight				0.3		g
Approximate weight				0.01		oz.
Marking device		Case style TO-252AA (D-PAK)		8EWH	06FNH	



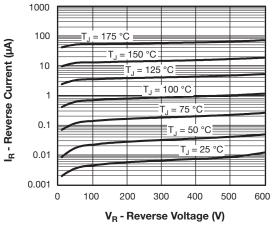
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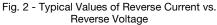


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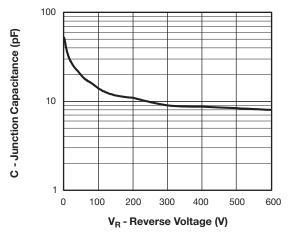


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

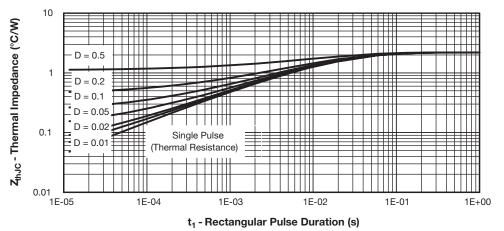
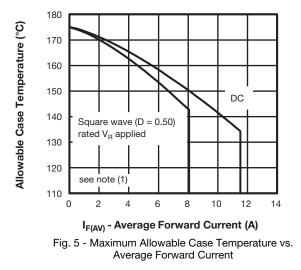


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

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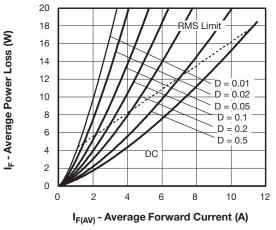
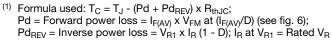


Fig. 6 - Forward Power Loss Characteristics

Note



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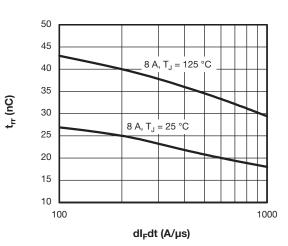
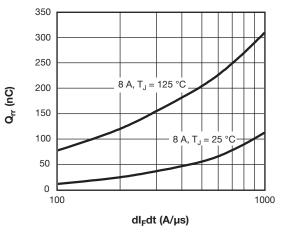


Fig. 7 - Typical Reverse Recovery Time vs. dl_F/dt





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VS-8EWH06FNHM3

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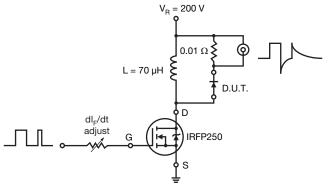
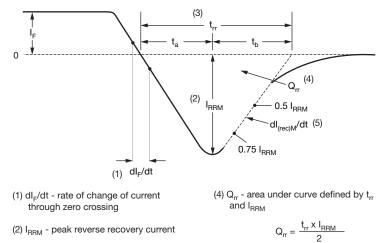


Fig. 9 - Reverse Recovery Parameter Test Circuit



(3) t_{rr} - reverse recovery time measured from zero crossing point of negative going I_F to point where a line passing through 0.75 I_{RRM} and 0.50 I_{RRM} extrapolated to zero current. (5) dl_{(rec)M}/dt - peak rate of change of current during t_b portion of t_{rr}

Fig. 10 - Reverse Recovery Waveform and Definitions

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ORDERING INFORMATION TABLE

Device code	VS-	8	Е	w	н	06	FN	TRL	Н	М3
	1	2	3	4	5	6	7	8	9	10
	믐	3 - Circuit configuration:								
	4	- Pac	E = single diode Package identifier: W = D-PAK							
	7	- Vol - FN	H = hyperfast recovery Voltage rating (06 = 600 V) FN = TO-252AA							
	8	• T	 None = tube TR = tape and reel TRL = tape and reel (left oriented) 							
	9 10	- H = - Env	 TRR = tape and reel (right oriented) H = AEC-Q101 qualified Environmental digit: M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free 							

ORDERING INFORMATION (Example)								
PREFERRED P/N	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION						
VS-8EWH06FNHM3	75	3000	Antistatic plastic tube					
VS-8EWH06FNTRHM3	2000	2000	13" diameter reel					
VS-8EWH06FNTRRHM3	3000	3000	13" diameter reel					
VS-8EWH06FNTRLHM3	3000	3000	13" diameter reel					

LINKS TO RELATED DOCUMENTS					
Dimensions	www.vishay.com/doc?95519				
Part marking information	www.vishay.com/doc?95518				
Packaging information	www.vishay.com/doc?95033				



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